

IRS2011(S)PbF

HIGH AND LOW SIDE DRIVER

Features

- Floating channel designed for bootstrap operation
- Fully operational up to +200 V
- Tolerant to negative transient voltage, dV/dt immune
- Gate drive supply range from 10 V to 20 V
- Independent low and high side channels
- Input logic HIN/LIN active high
- Undervoltage lockout for both channels
- 3.3 V and 5 V input logic compatible
- CMOS Schmitt-triggered inputs with pull-down
- Matched propagation delay for both channels

Applications

- Audio Class D amplifiers
- High power DC-DC SMPS converters
- Other high frequency applications

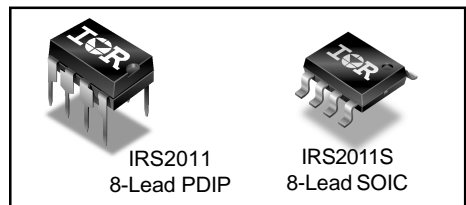
Description

The IRS2011 is a high power, high speed power MOSFET driver with independent high and low side referenced output channels, ideal for Audio Class D and DC-DC converter applications. Logic inputs are compatible with standard CMOS or LSTTL output, down to 3.0 V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Propagation delays are matched to simplify use in high frequency applications. The floating channel can be used to drive an N-channel power MOSFET in the high side configuration which operates up to 200 V. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction.

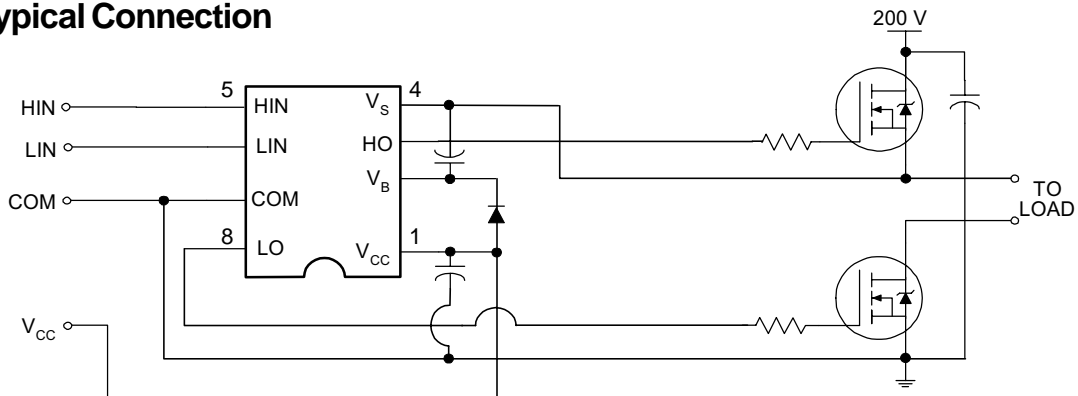
Product Summary

V_{OFFSET}	200 V max.
$I_{\text{O+/-}}$	1.0 A / 1.0 A typ.
V_{OUT}	10 V - 20 V
$t_{\text{on/off}}$	60 ns typ.
Delay Matching	20 ns max.

Packages



Typical Connection



(Refer to Lead Assignments for correct configuration). This diagram shows electrical connections only. Please refer to our Application Notes and DesignTips for proper circuit board layout.

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units	
V_B	High side floating supply voltage	-0.3	220 (Note 1)	V	
V_S	High side floating supply offset voltage	$V_B - 20$	$V_B + 0.3$		
V_{HO}	High side floating output voltage	$V_S - 0.3$	$V_B + 0.3$		
V_{CC}	Low side fixed supply voltage	-0.3	20 (Note 1)		
V_{LO}	Low side output voltage	-0.3	$V_{CC} + 0.3$		
V_{IN}	Logic input voltage (HIN & LIN)	-0.3	$V_{CC} + 0.3$		
dV_S/dt	Allowable offset supply voltage transient (Fig. 2)	—	50	V/ns	
P_D	Package power dissipation @ $T_A = +25\text{ }^\circ\text{C}$	(8-lead DIP)	—	1.0	W
		(8-lead SOIC)	—	0.625	
R_{THJA}	Thermal resistance, junction to ambient	(8-lead DIP)	—	125	$^\circ\text{C/W}$
		(8-lead SOIC)	—	200	
T_J	Junction temperature	—	150	$^\circ\text{C}$	
T_S	Storage temperature	-55	150		
T_L	Lead temperature (soldering, 10 seconds)	—	300		

Note 1: All supplies are fully tested at 25 V and an internal 20 V clamp exists for each supply.

Recommended Operating Conditions

For proper operation the device should be used within the recommended conditions. The V_S and COM offset ratings are tested with all supplies biased at a 15 V differential.

Symbol	Definition	Min.	Max.	Units
V_B	High side floating supply absolute voltage	$V_S + 10$	$V_S + 20$	V
V_S	High side floating supply offset voltage	Note 2	200	
V_{HO}	High side floating output voltage	V_S	V_B	
V_{CC}	Low side fixed supply voltage	10	20	
V_{LO}	Low side output voltage	0	V_{CC}	
V_{IN}	Logic input voltage (HIN & LIN)	COM	5.5	
T_A	Ambient temperature	-40	125	

Note 2: Logic operational for V_S of -5 V to +200 V. Logic state held for V_S of -5 V to $-V_{BS}$.

Dynamic Electrical Characteristics

$V_{BIAS} (V_{CC}, V_{BS}) = 15\text{ V}$, $C_L = 1000\text{ pF}$, $T_A = 25\text{ }^\circ\text{C}$ unless otherwise specified. Figure 1 shows the timing definitions.

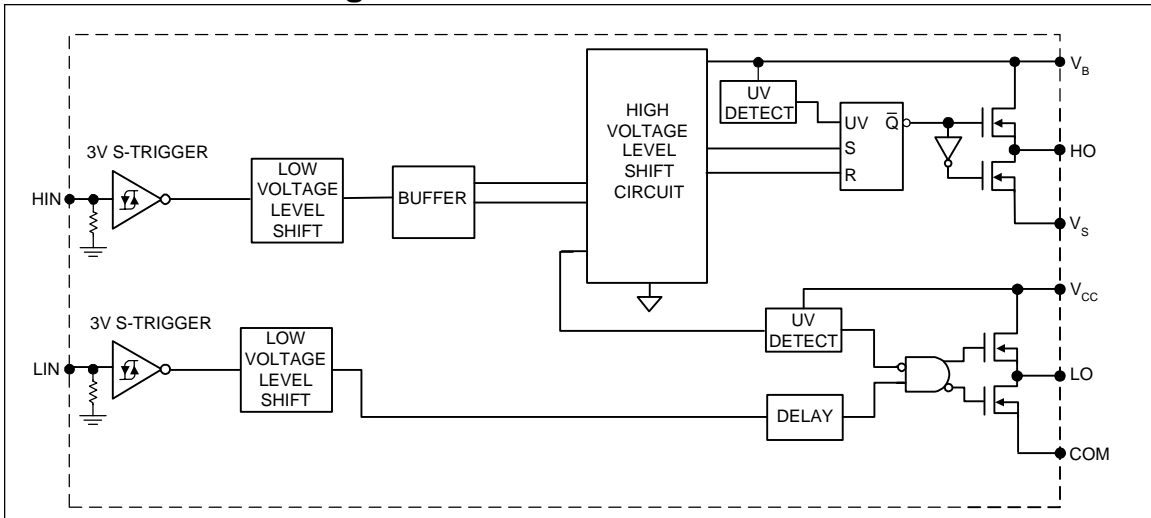
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
t_{on}	Turn-on propagation delay	—	60	80	ns	$V_S = 0\text{ V}$
t_{off}	Turn-off propagation delay	—	60	80		$V_S = 200\text{ V}$
t_r	Turn-on rise time	—	25	40		
t_f	Turn-off fall time	—	15	35		
DM1	Turn-on delay matching $ t_{on}(H) - t_{on}(L) $	—	—	20		
DM2	Turn-off delay matching $ t_{off}(H) - t_{off}(L) $	—	—	20		

Static Electrical Characteristics

$V_{BIAS} (V_{CC}, V_{BS}) = 15\text{ V}$, and $T_A = 25\text{ }^\circ\text{C}$ unless otherwise specified. The V_{IN} , V_{TH} , and I_{IN} parameters are referenced to COM and are applicable to all logic input leads: HIN and LIN. The V_O and I_O parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
V_{IH}	Logic "1" input voltage	2.5	—	—	V	$V_{CC} = 10\text{ V} - 20\text{ V}$
V_{IL}	Logic "0" input voltage	—	—	0.7		$I_O = 0\text{ A}$
V_{OH}	High level output voltage, $V_{BIAS} - V_O$	—	—	1.2		$I_O = 20\text{ mA}$
V_{OL}	Low level output voltage, V_O	—	—	0.1		
I_{LK}	Offset supply leakage current	—	—	50	μA	$V_B = V_S = 200\text{ V}$
I_{QBS}	Quiescent V_{BS} supply current	—	120	210		$V_{IN} = 0\text{ V}$ or 3.3 V
I_{QCC}	Quiescent V_{CC} supply current	—	200	300		$V_{IN} = 3.3\text{ V}$
I_{IN+}	Logic "1" input bias current	—	3	10		$V_{IN} = 0\text{ V}$
I_{IN-}	Logic "0" input bias current	—	—	1.0		
V_{BSUV+}	V_{BS} supply undervoltage positive going threshold	8.3	9.0	9.7	V	
V_{BSUV-}	V_{BS} supply undervoltage negative going threshold	7.5	8.2	8.9		
V_{CCUV+}	V_{CC} supply undervoltage positive going threshold	8.3	9.0	9.7		
V_{CCUV-}	V_{CC} supply undervoltage negative going threshold	7.5	8.2	8.9		
I_{O+}	Output high short circuit pulsed current	—	1.0	—	A	$V_O = 0\text{ V}$, $PW = 10\text{ }\mu\text{s}$
I_{O-}	Output low short circuit pulsed current	—	1.0	—		$V_O = 15\text{ V}$, $PW = 10\text{ }\mu\text{s}$

Functional Block Diagram



Lead Definitions

Symbol	Description
HIN	Logic input for high side gate driver output (HO), in phase
LIN	Logic input for low side gate driver output (LO), in phase
VB	High side floating supply
HO	High side gate drive output
VS	High side floating supply return
VCC	Low side supply
LO	Low side gate drive output
COM	Low side return

Lead Assignments

<p>8-Lead SOIC</p> <p>IRS2011S</p>	<p>8-Lead PDIP</p> <p>IRS2011</p>
Part Number	

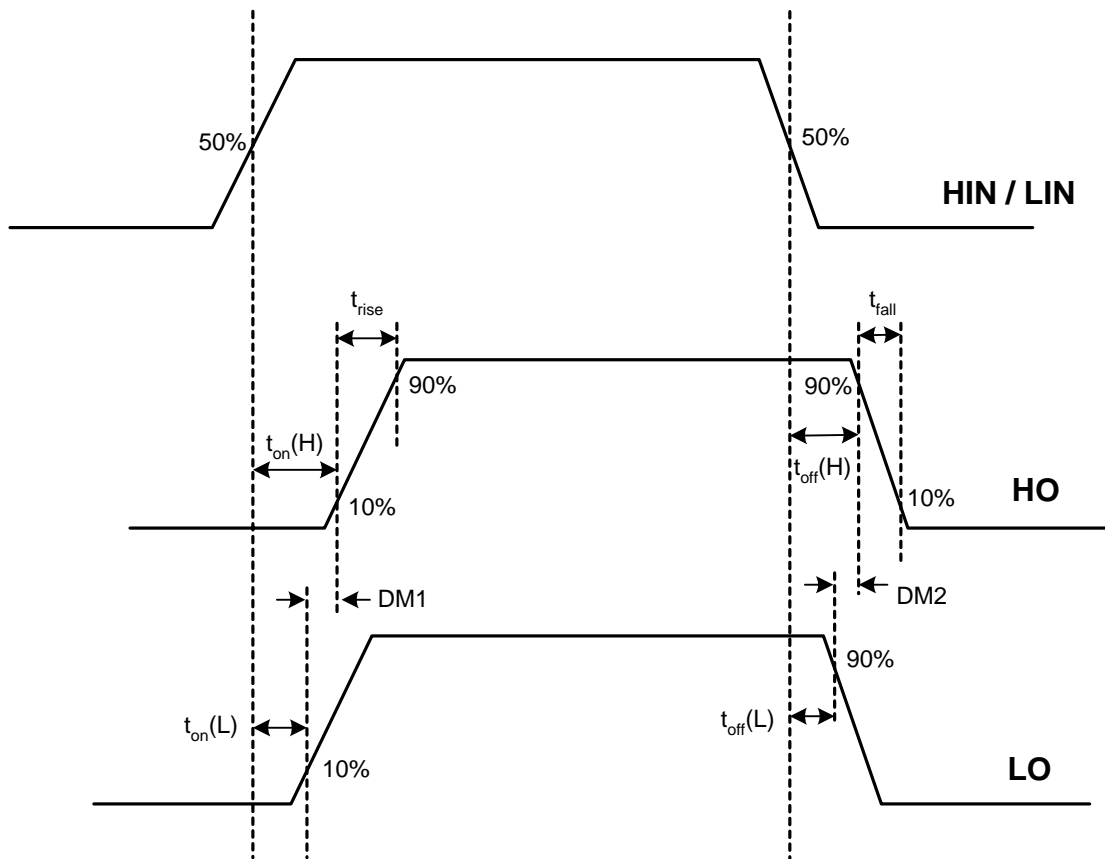


Figure 1. Timing Diagram

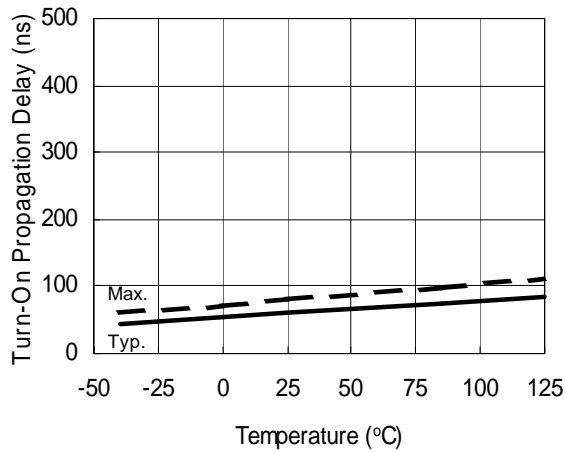


Figure 2A. Turn-On Propagation Delay vs. Temperature

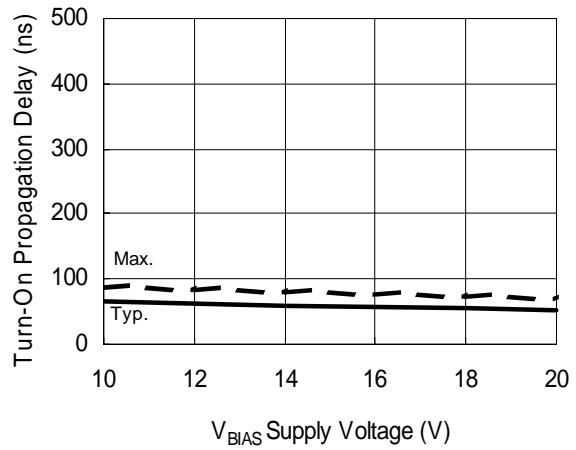


Figure 2B. Turn-On Propagation Delay vs. Supply Voltage

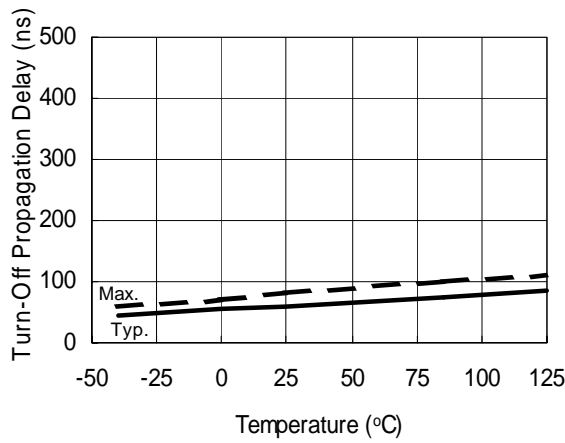


Figure 3A. Turn-Off Propagation Delay vs. Temperature

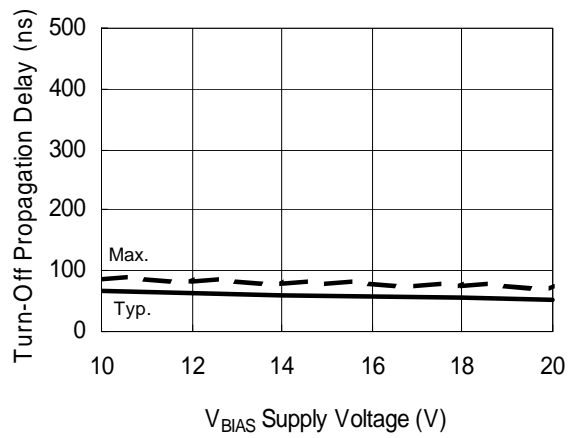


Figure 3B. Turn-Off Propagation Delay vs. Supply Voltage

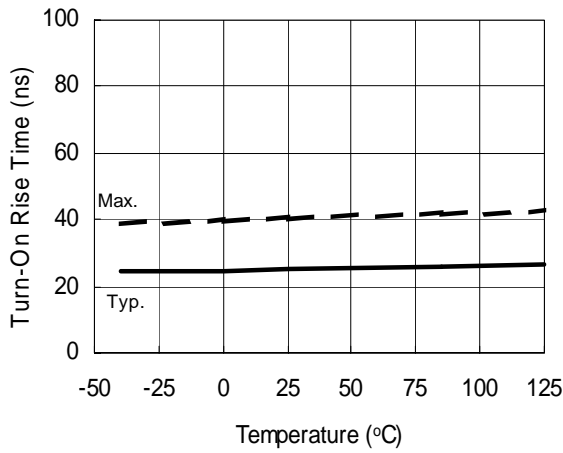


Figure 4A. Turn-On Rise Time vs. Temperature

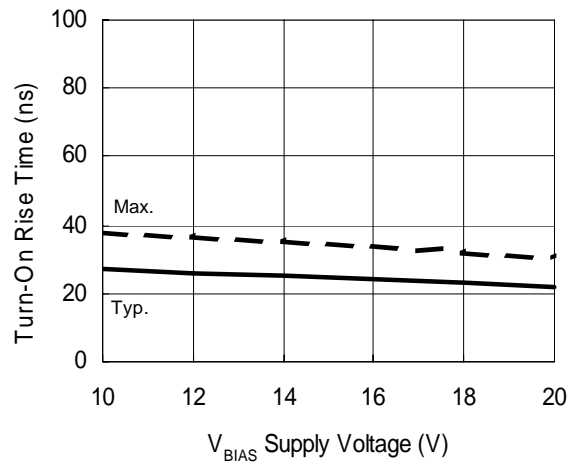


Figure 4B. Turn-On Rise Time vs. Supply Voltage

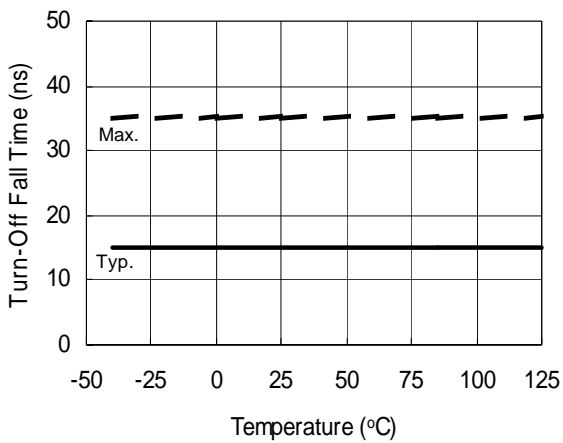


Figure 5A. Turn-Off Fall Time vs. Temperature

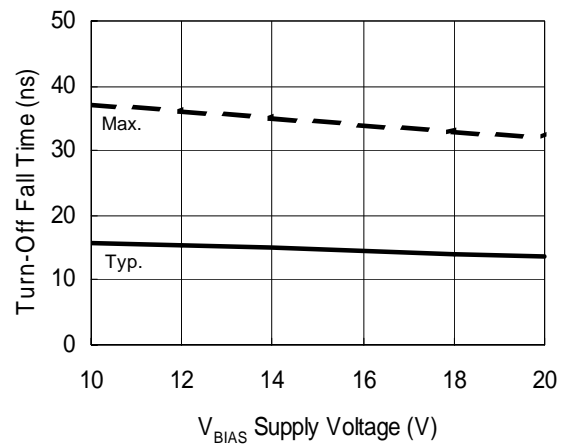


Figure 5B. Turn-Off Fall Time vs. Supply Voltage

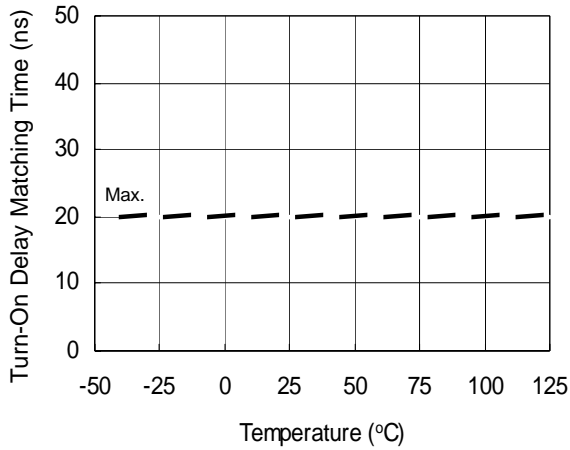


Figure 6A. Turn-On Delay Matching Time vs. Temperature

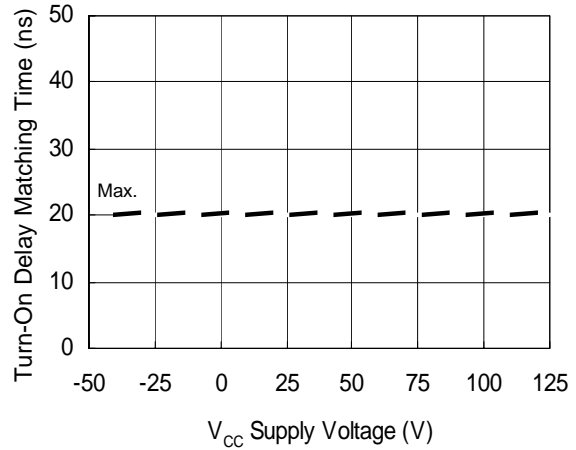


Figure 6B. Turn-On Delay Matching Time vs. Supply Voltage

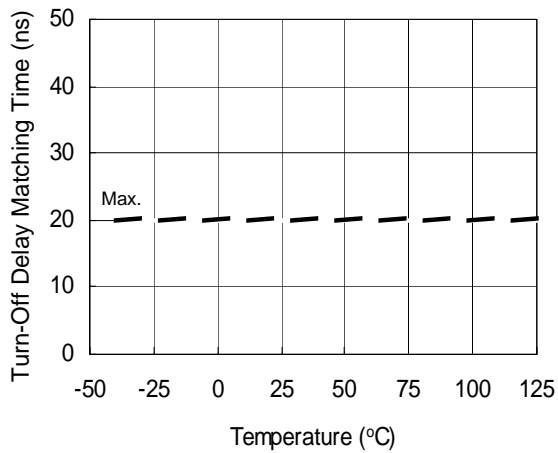


Figure 7A. Turn-Off Delay Matching Time vs. Temperature

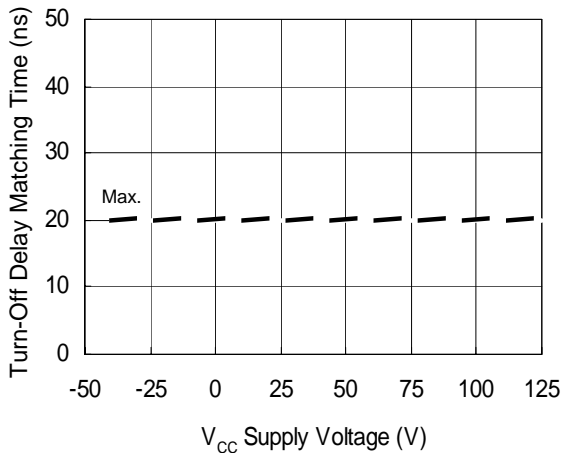


Figure 7B. Turn-Off Delay Matching Time vs. Supply Voltage

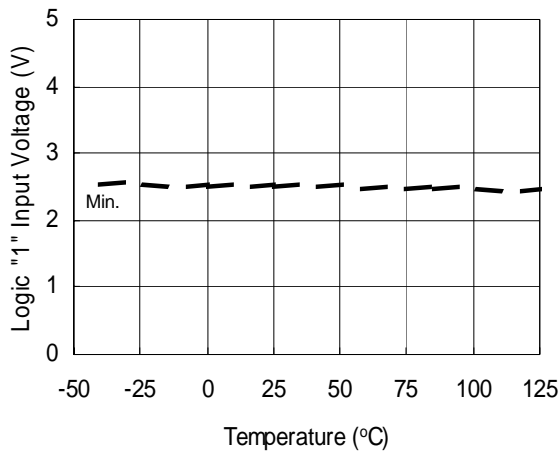


Figure 8A. Logic "1" Input Voltage vs. Temperature

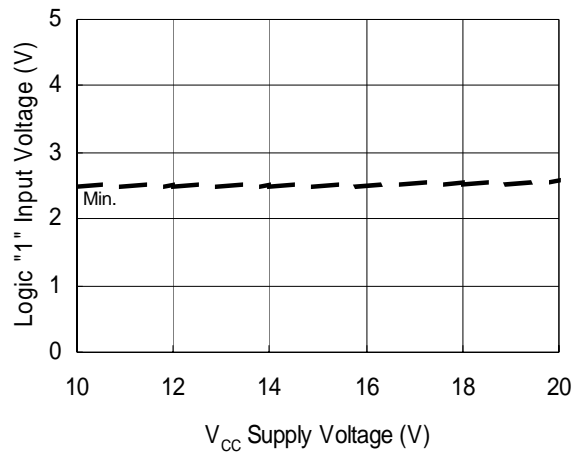


Figure 8B. Logic "1" Input Voltage vs. Supply Voltage

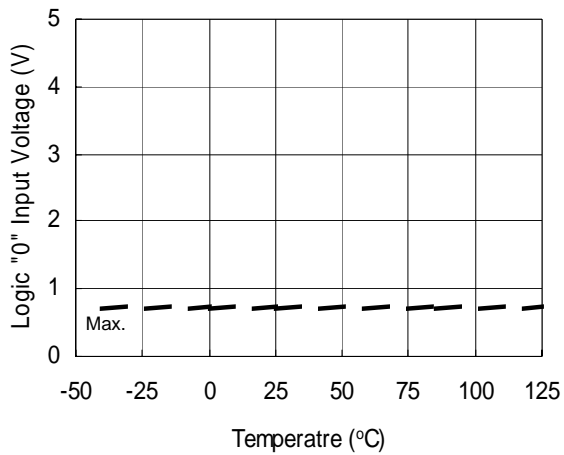


Figure 9A. Logic "0" Input Voltage vs. Temperature

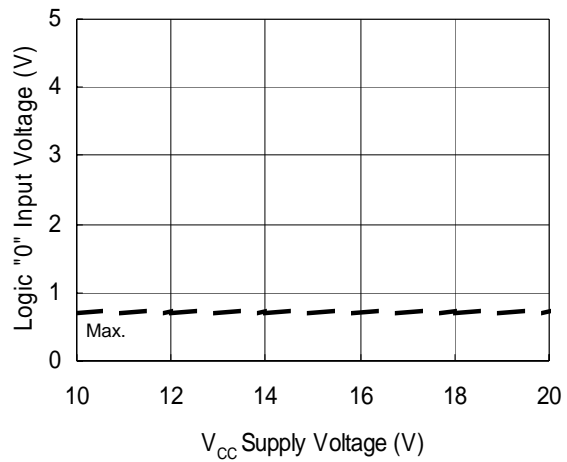


Figure 9B. Logic "0" Input Voltage vs. Supply Voltage

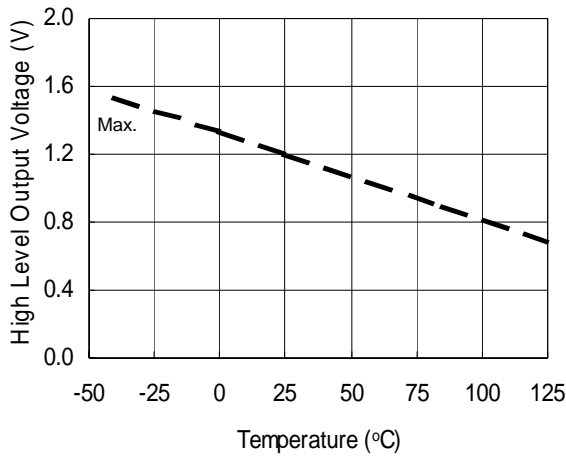


Figure 10A. High Level Output vs. Temperature

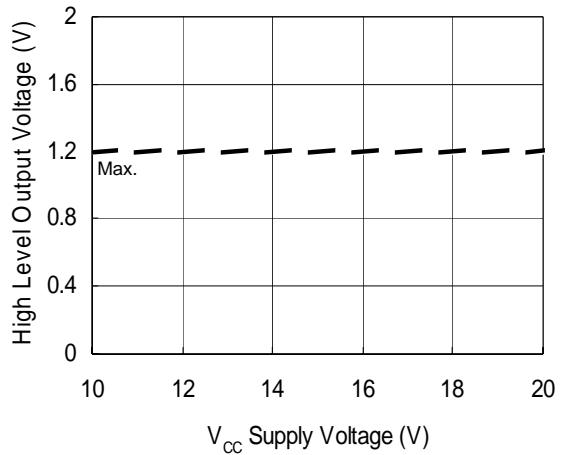


Figure 10B. High Level Output vs. Supply Voltage

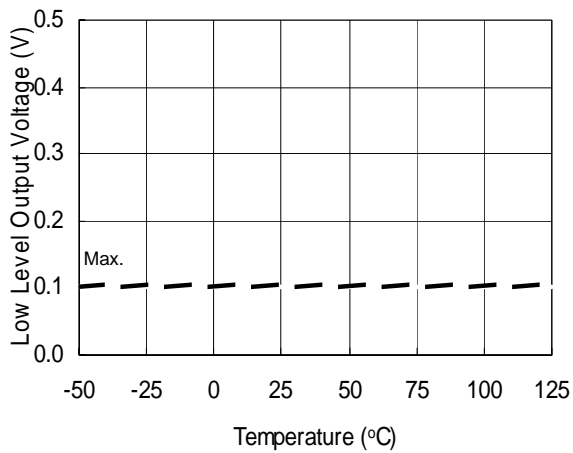


Figure 11A. Low Level Output vs. Temperature

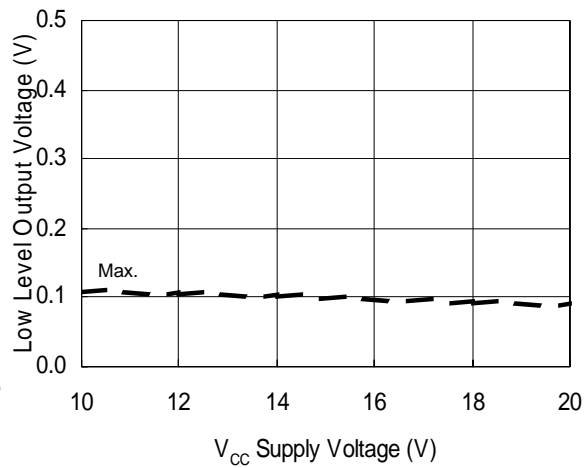


Figure 11B. Low Level Output vs. Supply Voltage

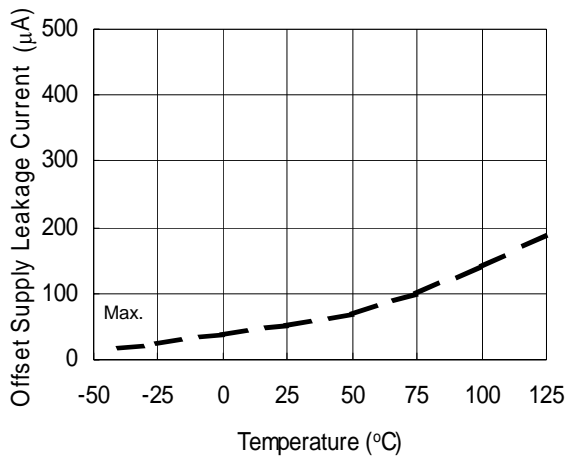


Figure 12A. Offset Supply Leakage Current vs. Temperature

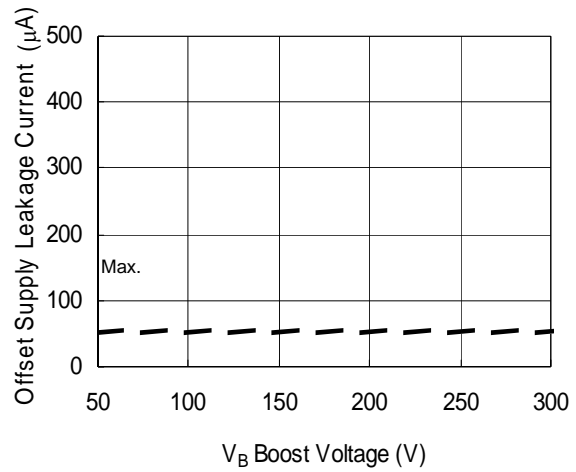


Figure 12B. Offset Supply Leakage Current vs. Supply Voltage

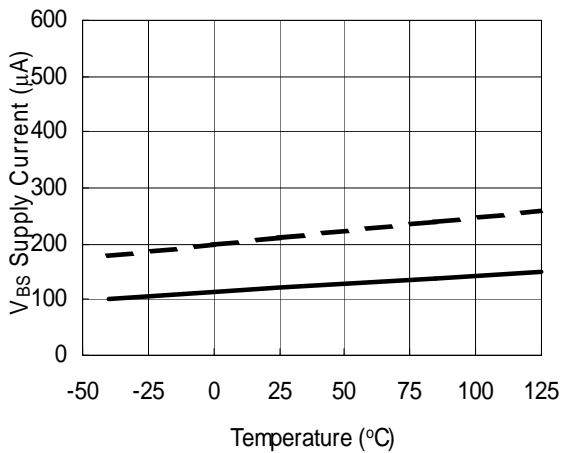


Figure 13A. V_{BS} Supply Current vs. Temperature

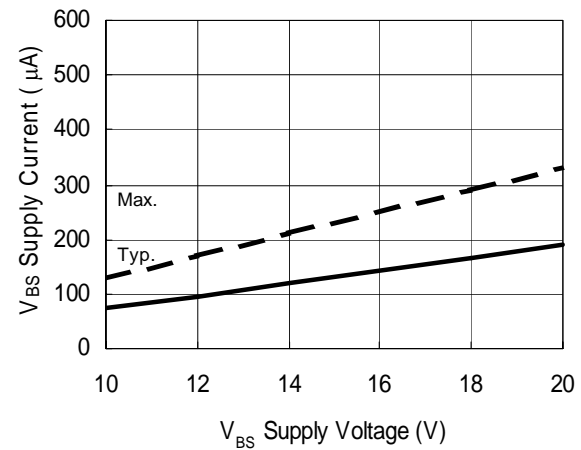


Figure 13B. V_{BS} Supply Current vs. Supply Voltage

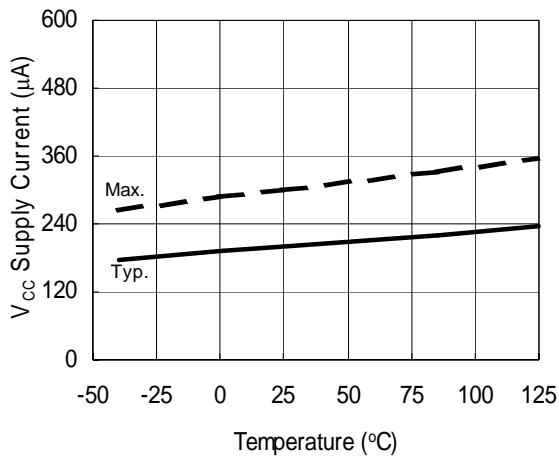


Figure 14A. V_{CC} Supply Current vs. Temperature

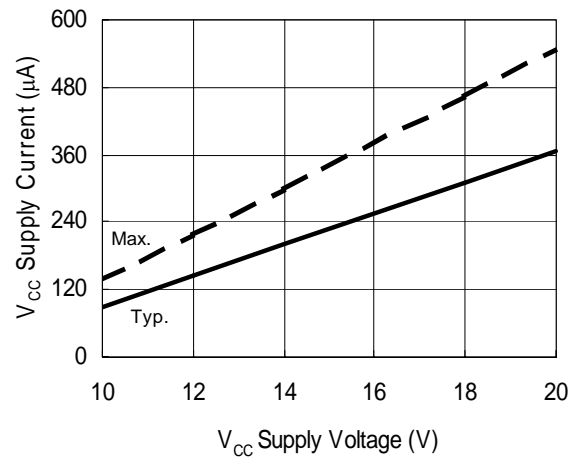


Figure 14B. V_{CC} Supply Current vs. Supply Voltage

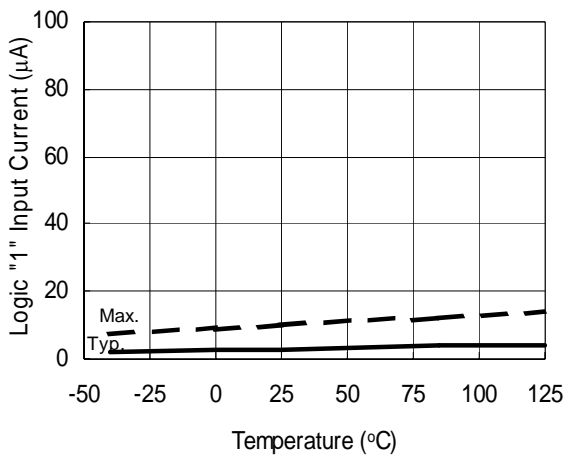


Figure 15A. Logic "1" Input Current vs. Temperature

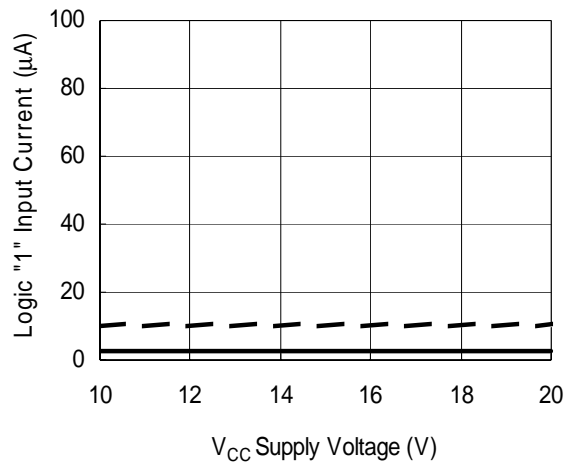


Figure 15B. Logic "1" Input Current vs. Supply Voltage

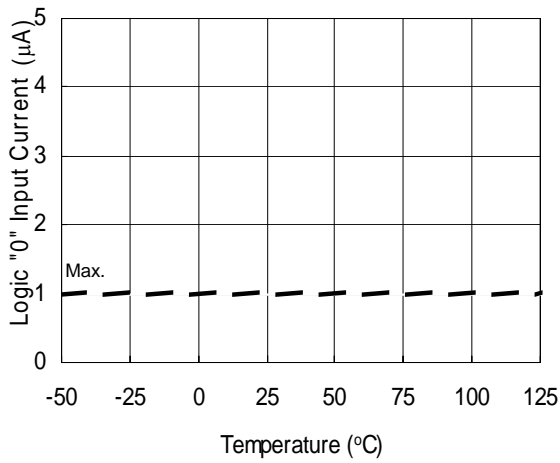


Figure 16A. Logic "0" Input Current vs. Temperature

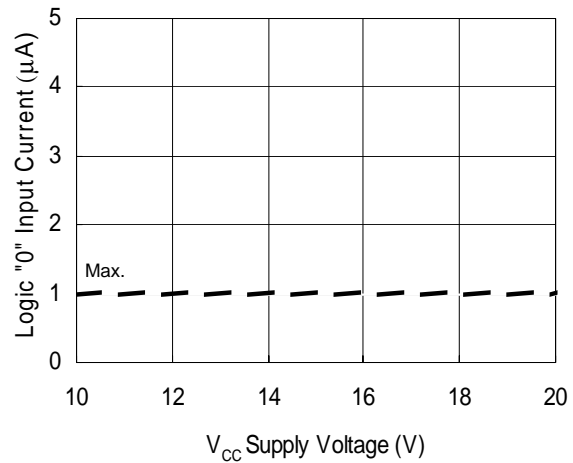


Figure 16B. Logic "0" Input Current vs. Supply Voltage

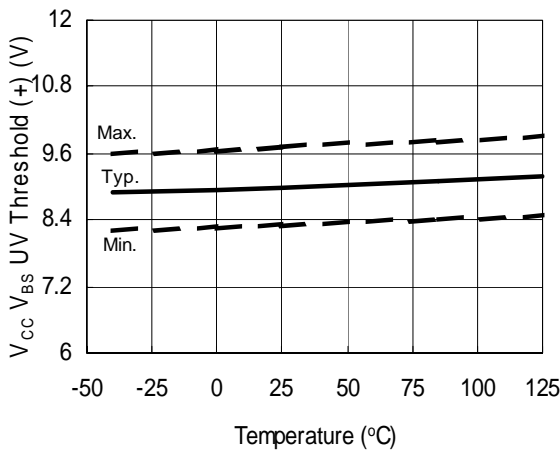


Figure 17. V_{CC} and V_{BS} Undervoltage Threshold (+) vs. Temperature

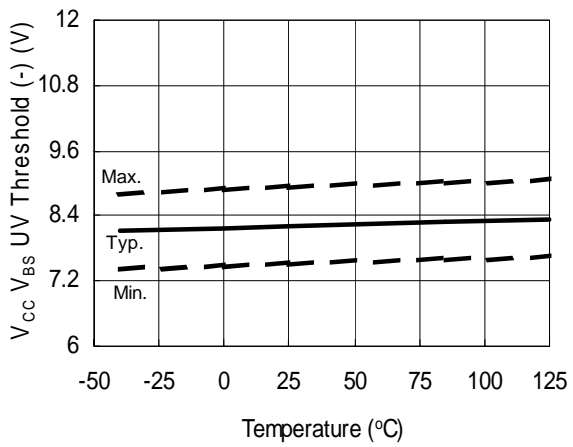


Figure 18. V_{CC} and V_{BS} Undervoltage Threshold (-) vs. Temperature

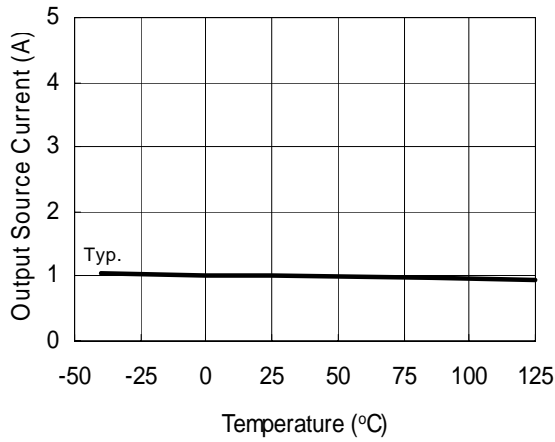


Figure 19A. Output Source Current vs. Temperature

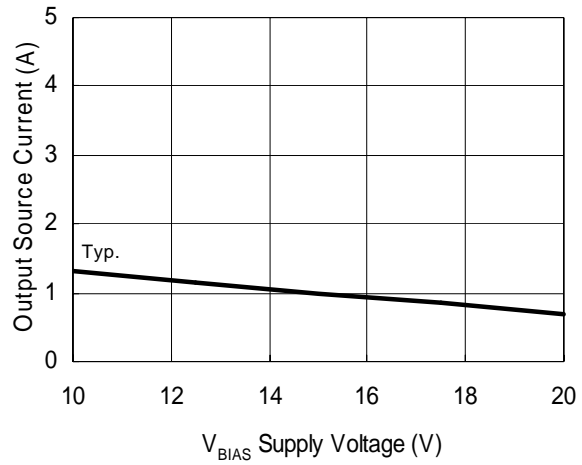


Figure 19B. Output Source Current vs. Supply Voltage

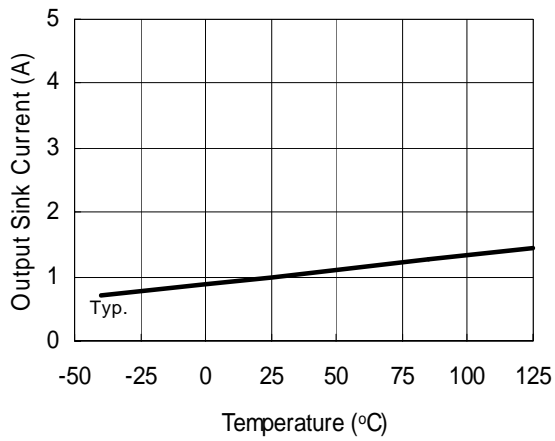


Figure 20A. Output Sink Current vs. Temperature

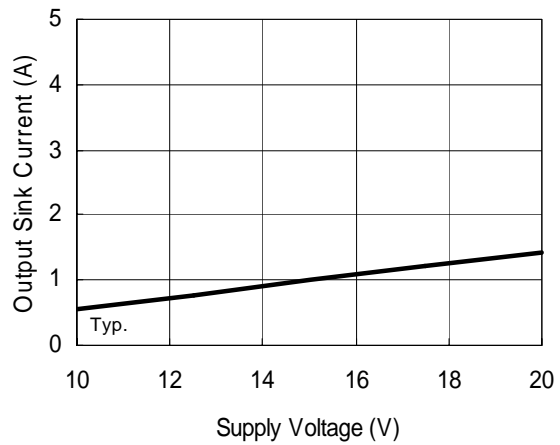


Figure 20B. Output Sink Current vs. Supply Voltage

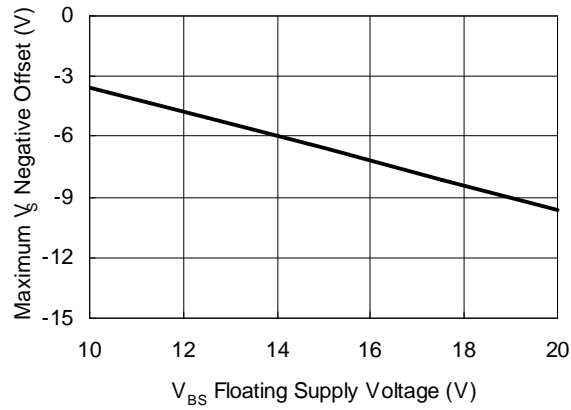


Figure 21. Maximum V_s Negative Offset vs V_{BS} Floating Supply Voltage

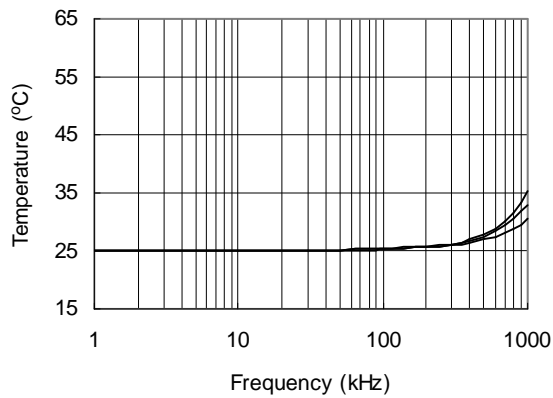


Figure 22. IRS2011S vs. Frequency (IRFBC20)
 $R_{gate}=33\ \Omega$, $V_{CC}=12\ \text{V}$

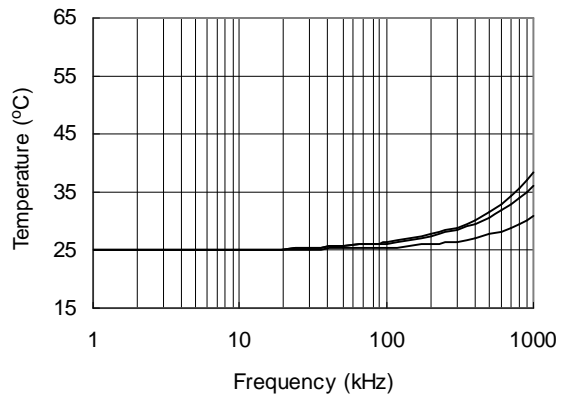


Figure 23. IRS2011S vs. Frequency (IRFBC30)
 $R_{gate}=22\ \Omega$, $V_{CC}=12\ \text{V}$

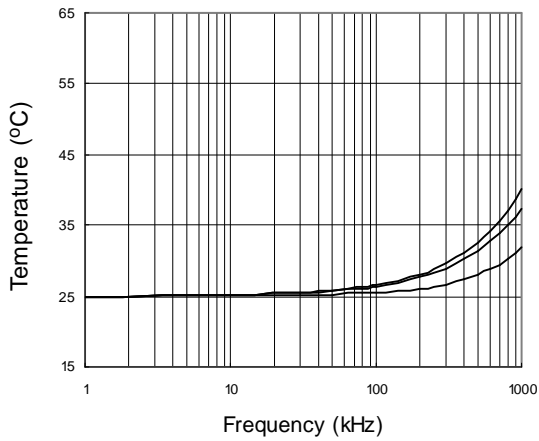


Figure 24. IRS2011S vs. Frequency (IRFBC40)
 $R_{gate}=15\text{ W}, V_{cc}=12\text{ V}$

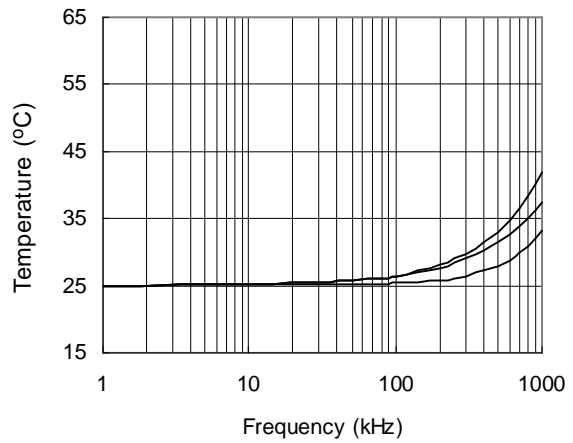


Figure 25. IRS2011S vs. Frequency (IRFB23N15D)
 $R_{gate}=10\text{ W}, V_{cc}=12\text{ V}$

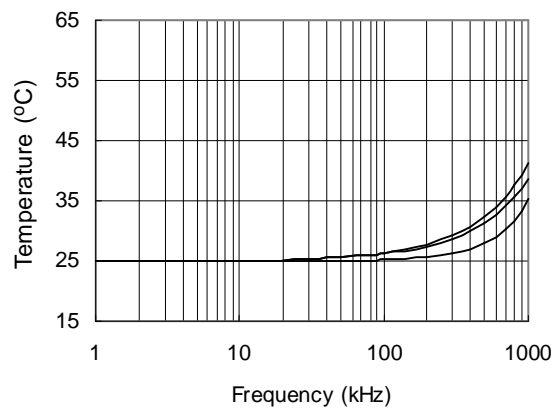
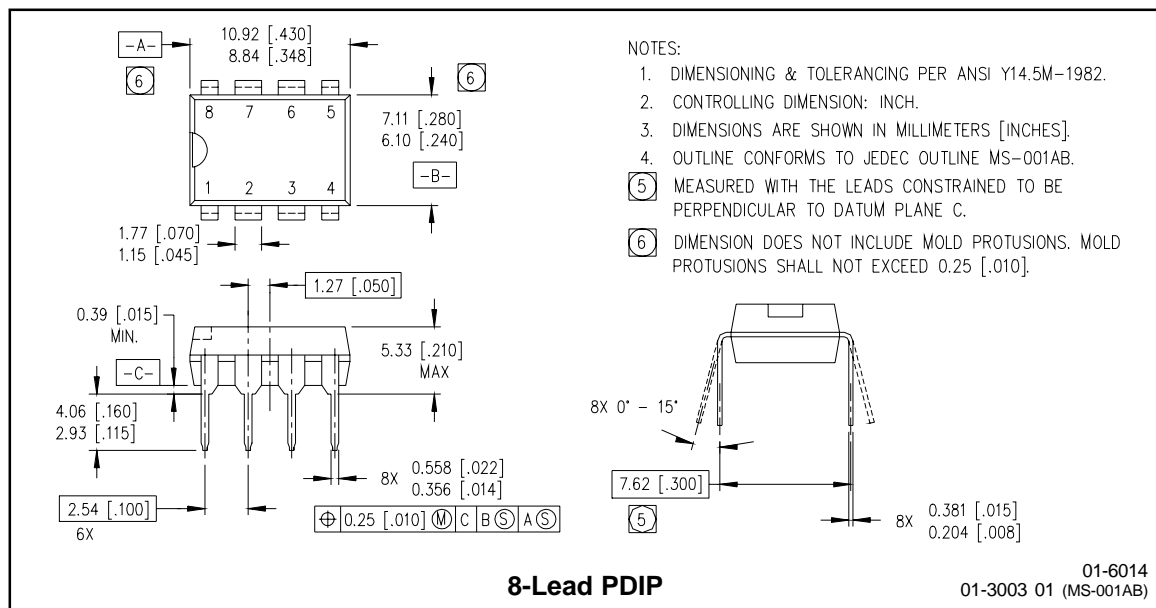
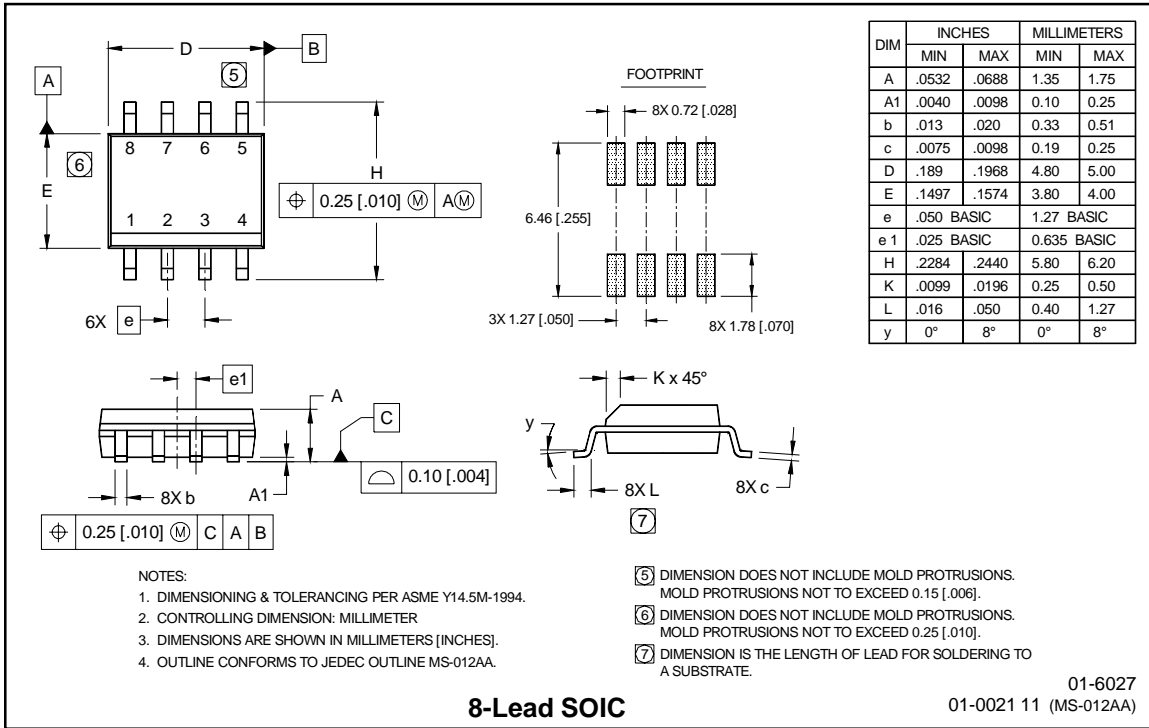
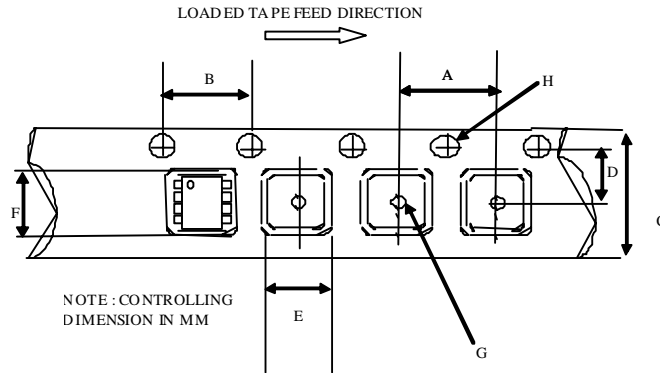


Figure 26. IRS2011S vs. Frequency (IRFB4212)
 $R_{gate}=10\text{ W}, V_{cc}=12\text{ V}$

Case outlines

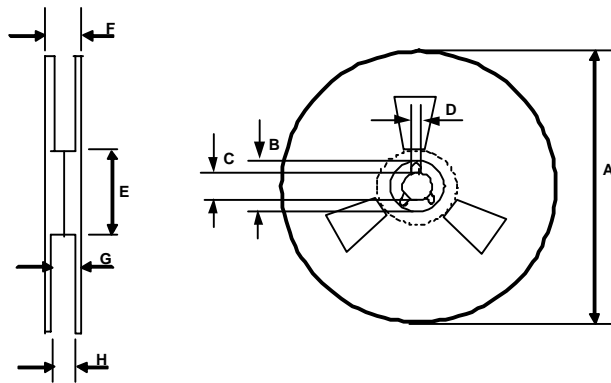


Tape & Reel 8-lead SOIC



CARRIER TAPE DIMENSION FOR 8SOICN

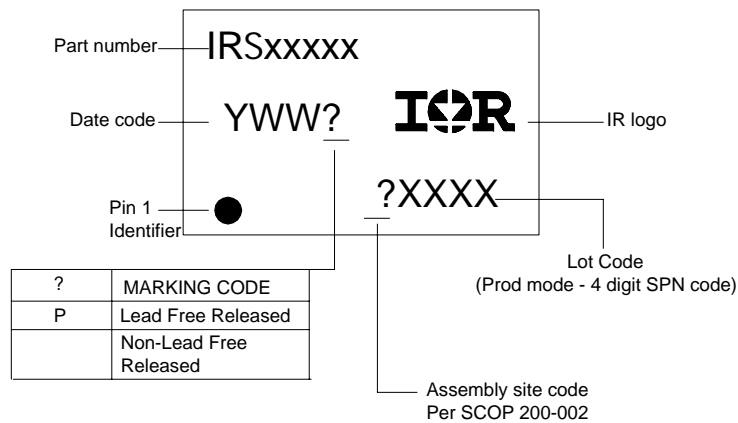
Code	Metric		Imperial	
	Min	Max	Min	Max
A	7.90	8.10	0.311	0.318
B	3.90	4.10	0.153	0.161
C	11.70	12.30	0.46	0.484
D	5.45	5.55	0.214	0.218
E	6.30	6.50	0.248	0.255
F	5.10	5.30	0.200	0.208
G	1.50	n/a	0.059	n/a
H	1.50	1.60	0.059	0.062



REEL DIMENSIONS FOR 8SOICN

Code	Metric		Imperial	
	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
B	20.95	21.45	0.824	0.844
C	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	18.40	n/a	0.724
G	14.50	17.10	0.570	0.673
H	12.40	14.40	0.488	0.566

LEADFREE PART MARKING INFORMATION



ORDER INFORMATION

8-Lead PDIP IRS2011PbF
 8-Lead SOIC IRS2011SPbF
 8-Lead SOIC Tape & Reel IRS2011STRPbF